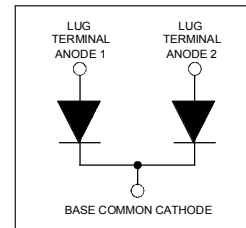


International
IOR Rectifier

203CNQ100PbF

SCHOTTKY RECTIFIER

200 Amp



Major Ratings and Characteristics

Characteristics	Value	Units
$I_{F(AV)}$ Rectangular waveform	200	A
V_{RRM}	100	V
I_{FSM} @tp = 5 μ s sine	12,800	A
V_F @100Apk, $T_J = 125^\circ\text{C}$ (per leg)	0.70	V
T_J range	-55 to 175	$^\circ\text{C}$

Description/ Features

The 203CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 $^\circ\text{C}$ junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, free-wheeling diodes, welding, and reverse battery protection.

- 175 $^\circ\text{C}$ T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free

Case Styles



TO-244

Voltage Ratings

Part number	203CNQ100PbF
V _R Max. DC Reverse Voltage (V)	100
V _{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	203CNQ	Units	Conditions
I _{F(AV)} Max. Average Forward Current (Per Leg) * See Fig. 5 (Per Device)	100	A	50% duty cycle @ T _C = 142 °C, rectangular wave form
	200		
I _{FSM} Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg) * See Fig. 7	12,800	A	5µs Sine or 3µs Rect. pulse 10ms Sine or 6ms Rect. pulse Following any rated load condition and with rated V _{RRM} applied
	1,700		
E _{AS} Non-Repetitive Avalanche Energy (Per Leg)	15	mJ	T _J = 25 °C, I _{AS} = 13 Amps, L = 0.2 mH
I _{AR} Repetitive Avalanche Current (Per Leg)	1	A	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. V _A = 1.5 x V _R typical

Electrical Specifications

Parameters	203CNQ	Units	Conditions
V _{FM} Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.86	V	@ 100A T _J = 25 °C
	1.03	V	@ 200A
	0.70	V	@ 100A T _J = 125 °C
	0.84	V	@ 200A
I _{RM} Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	3	mA	T _J = 25 °C
	40	mA	T _J = 125 °C V _R = rated V _R
V _{F(TO)} Threshold Voltage	0.50	V	T _J = T _J max.
r _t Forward Slope Resistance	1.08	mΩ	
C _T Max. Junction Capacitance (Per Leg)	2,650	pF	V _R = 5V _{DC} (test signal range 100Khz to 1Mhz) 25°C
L _S Typical Series Inductance (Per Leg)	7.0	nH	From top of terminal hole to mounting plane
dv/dt Max. Voltage Rate of Change (Rated V _R)	10000	V/ µs	

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	Min	Typ	Max	Units
T _J Max. Junction Temperature Range	- 55	-	175	°C
T _{Stg} Max. Storage Temperature Range	- 55	-	175	
R _{thJC} Thermal Resistance, Junction to Case	Per Leg	-	0.38	°C/W
	Per Module	-	0.19	K/W
R _{thCS} Thermal Resistance, Case to Heatsink	-	0.10	-	
Wt Weight	-	68 (2.4)	-	g (oz)
Mounting Torque	35.4 (4)	-	53.1 (6)	lbf*in
Mounting Torque Center Hole	30 (3.4)	-	40 (4.6)	(Nm)
Terminal Torque	30 (3.4)	-	44.2 (5)	
Vertical Pull	-	-	80	lbf.in
2 inch Lever Pull	-	-	35	

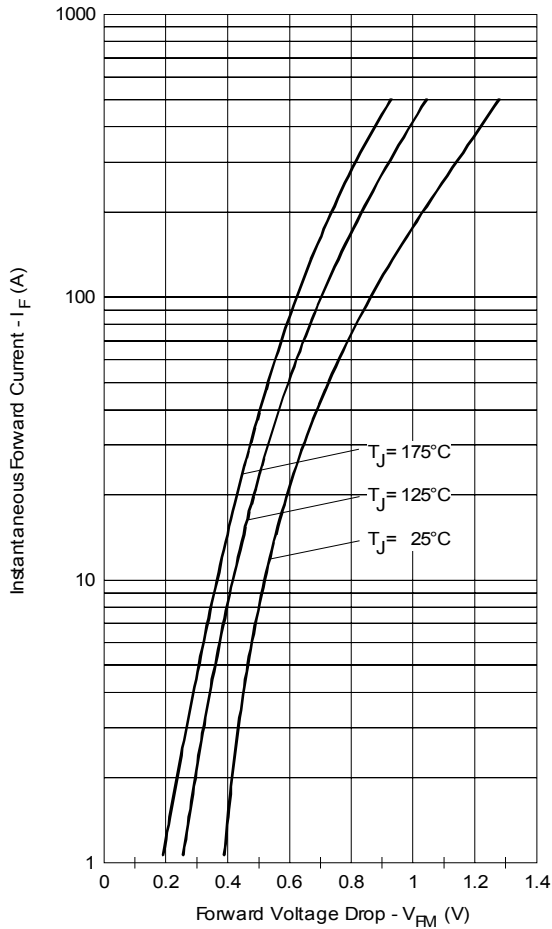


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

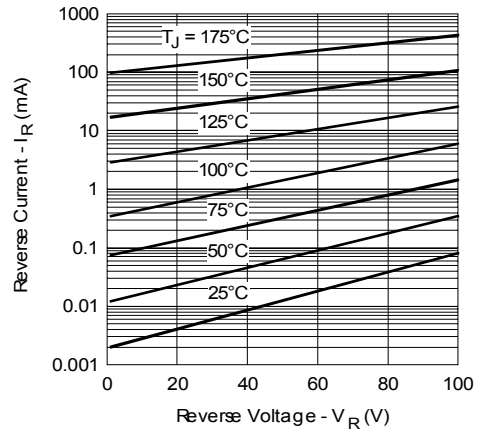


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

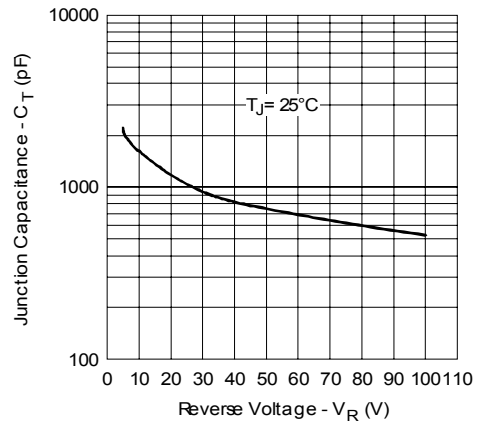


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

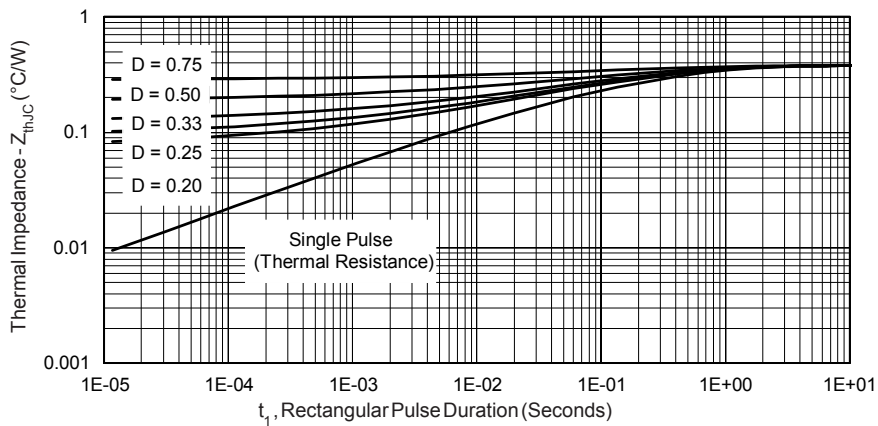


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

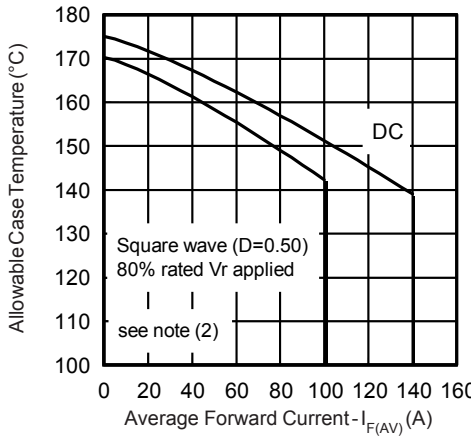


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current (Per Leg)

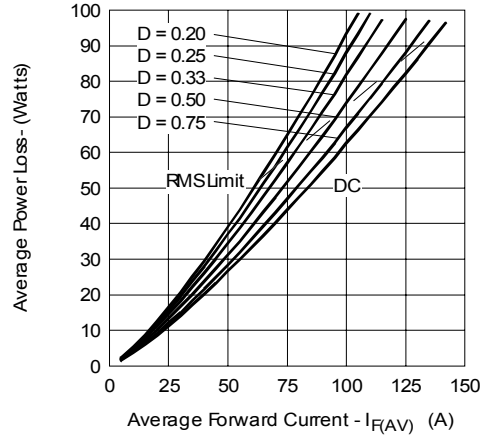


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

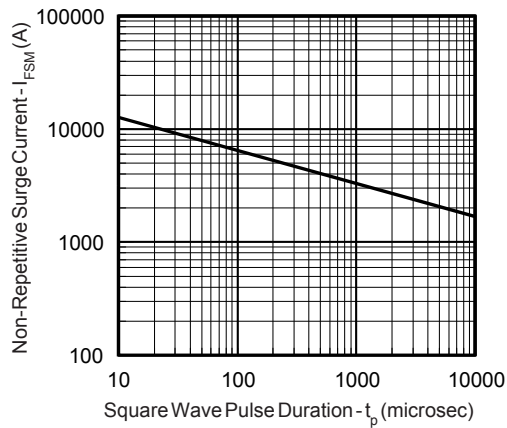


Fig. 7 - Max. Non-Repetitive Surge Current (Per Leg)

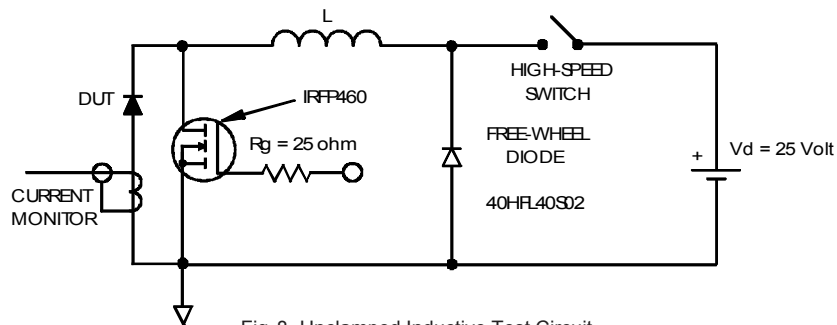
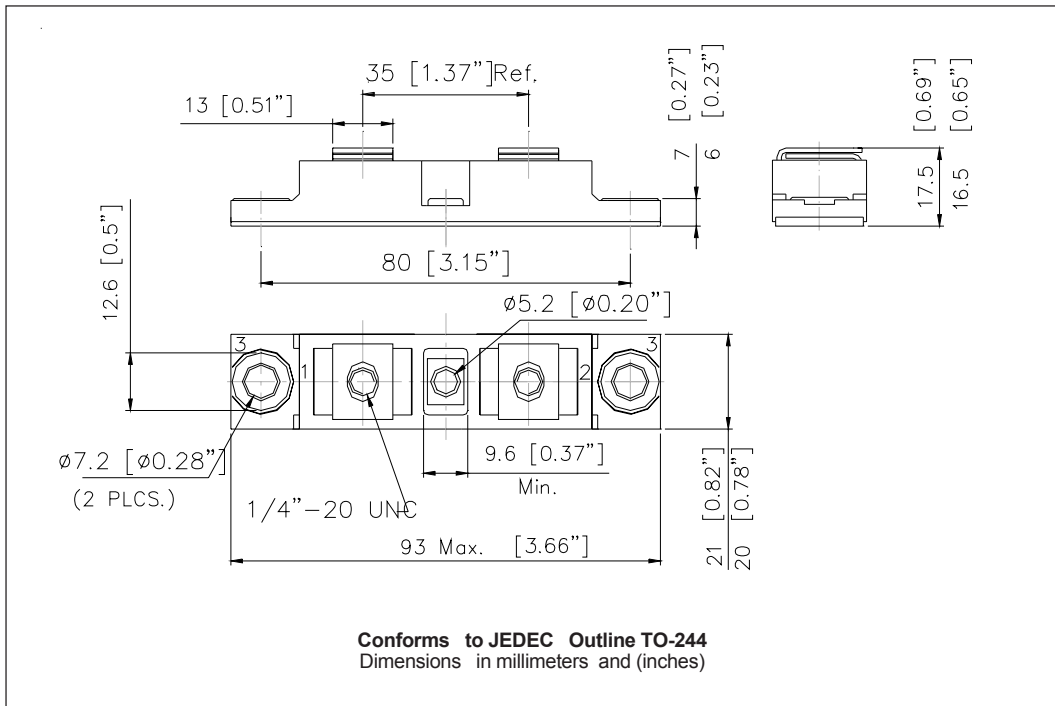


Fig. 8 - Unclamped Inductive Test Circuit

- (2) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_{R1} (1-D)$; $I_{R1} @ V_{R1} = 80\% \text{ rated } V_R$

Outline Table



Ordering Information Table

Device Code						
20	3	C	N	Q	100	PbF
①	②	③	④	⑤	⑥	⑦
1	-	Average Current Rating (x 10)				
2	-	Product Silicon Identification				
3	-	C = Circuit Configuration				
4	-	N = NOT Isolated				
5	-	Q = Schottky Rectifier Diode				
6	-	Voltage Rating (100 = 100V)				
7	-	Lead-Free				

203CNQ100PbF

Bulletin PD-21103 12/05

International
IR Rectifier

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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